TOSHIBA Transistor Silicon NPN Epitaxial Type (PCT process)

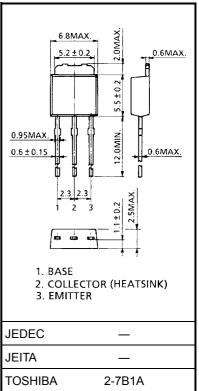
# 2SC3076

#### Power Amplifier Applications Power Switching Applications

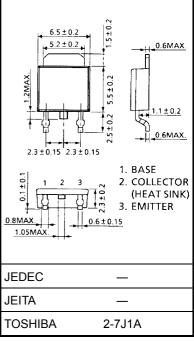
- Low collector saturation voltage:  $V_{CE (sat)} = 0.5 V (max) (I_C = 1 A)$
- Excellent switching time: t<sub>stg</sub> = 1.0 µs (typ.)
- Complementary to 2SA1241

#### Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit	
Collector-base voltage		V <sub>CBO</sub>	50	V	
Collector-emitter voltage		V <sub>CEO</sub>	50	V	
Emitter-base voltage		V <sub>EBO</sub>	5	V	
Collector current		Ι <sub>C</sub>	2	А	
Base current		Ι <sub>Β</sub>	1	А	
Collector power dissipation	Ta = 25°C	Pc	1.0	W	
	Tc = 25°C	- FC	10		
Junction temperature		Тj	150	°C	
Storage temperature range		T <sub>stg</sub>	-55 to 150	°C	



Weight: 0.36 g (typ.)



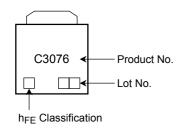
Weight: 0.36 g (typ.)

**Electrical Characteristics (Ta = 25°C)** 

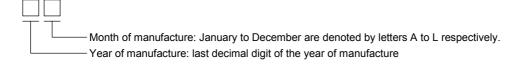
Chara	cteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off c	urrent	I <sub>CBO</sub>	V <sub>CB</sub> = 50 V, I <sub>E</sub> = 0	_	—	1.0	μA
Emitter cut-off cur	rent	I <sub>EBO</sub>	V <sub>EB</sub> = 5 V, I <sub>C</sub> = 0		_	1.0	μA
Collector-emitter breakdown voltage		V (BR) CEO	I <sub>C</sub> = 10 mA, I <sub>B</sub> = 0	50	_	_	V
DC current gain		h <sub>FE (1)</sub> (Note)	V <sub>CE</sub> = 2 V, I <sub>C</sub> = 0.5 A	70	_	240	
		h <sub>FE (2)</sub>	V <sub>CE</sub> = 2 V, I <sub>B</sub> = 1.5 A	40	_	_	
Collector-emitter	saturation voltage	V <sub>CE (sat)</sub>	I <sub>C</sub> = 1 A, I <sub>B</sub> = 0.05 A	_	_	0.5	V
Base-emitter satu	ration voltage	V <sub>BE (sat)</sub>	I <sub>C</sub> = 1 A, I <sub>B</sub> = 0.05 A	_	_	1.2	V
Transition frequency		f <sub>T</sub>	V <sub>CE</sub> = 2 V, I <sub>C</sub> = 0.5 A	_	80	_	MHz
Collector output capacitance		C <sub>ob</sub>	V <sub>CB</sub> = 10 V, I <sub>E</sub> = 0, f = 1 MHz	_	30	_	pF
Switching time	Turn-on time	t <sub>on</sub>	20 µs I <sub>B1</sub> OUTPUT	_	0.1	_	
	Storage time	t <sub>stg</sub>	$20 \ \mu s \qquad  B1 \qquad O \ O \ O \ O \ O \ O \ O \ O \ O \ O$	_	1.0		μs
	Fall time	t <sub>f</sub>	I <sub>B1</sub> = −I <sub>B2</sub> = 0.05 A, DUTY CYCLE ≤ 1%	_	0.1	_	

Note: hFE (1) classification O: 70 to 140, Y: 120 to 240

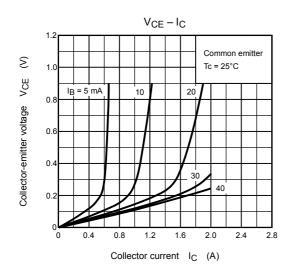
#### Marking

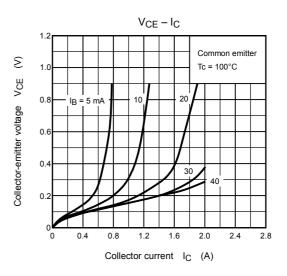


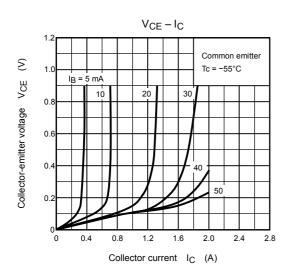
#### Explanation of Lot No.

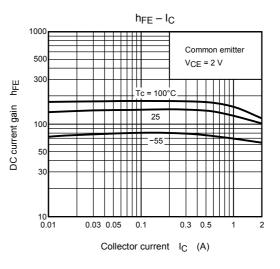


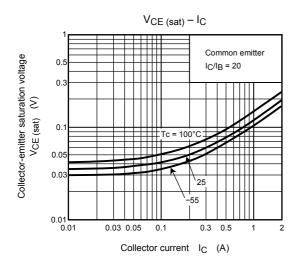
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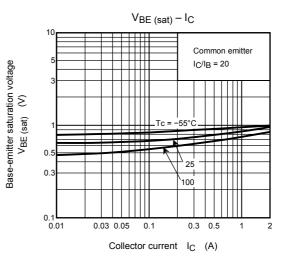




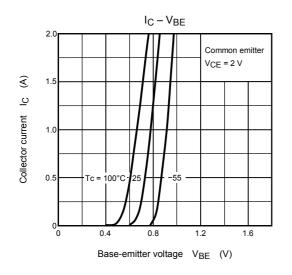


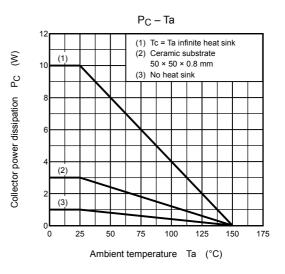


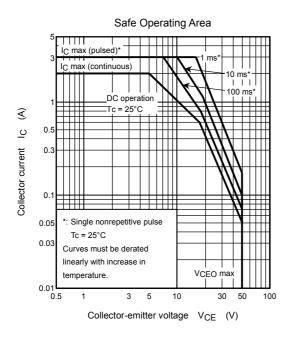




## TOSHIBA







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